

Multi-Mode PWM Controller with Integrated Protections

Features

- Low Start-Up Current (<2uA)
- Multi-Mode Operation
 CCM @ Heavy Load and Low Line
 QR-Like Operation @ Medium Load
 Green mode with Valley Skip at Light Load
 Burst Mode at No Load
- Accurate Over Current Protection
- Adjustment OVP on QRD Pin
- Output Short Protection
- Soft Driver
- 8ms Soft-start
- OVP (Over Voltage Protection) on Vcc Pin
- On Chip OTP Protection
- SOT-26 Package with Few External Components Needed

Description

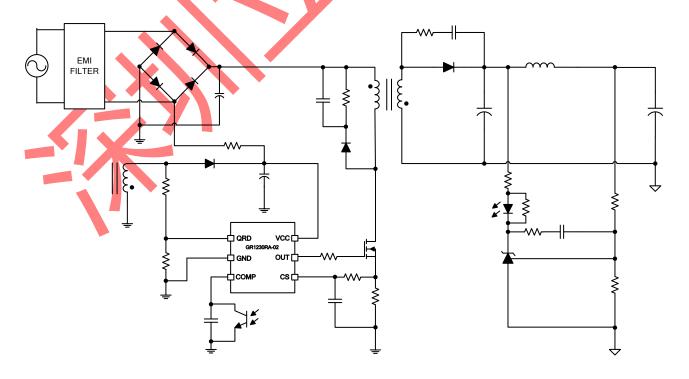
The GR1230RA-02 is a high performance

multi-mode (QR/CCM) PWM controller for flyback converter. It minimizes the components counts and is available in a tiny SOT-26 package. Those make it an ideal design for low cost application. It provides functions of low startup current, green- mode power-saving operation, VCC over-voltage protection, and QRD pin abnormal conditions sensing to prevent the circuit being damaged from the abnormal conditions.

Applications

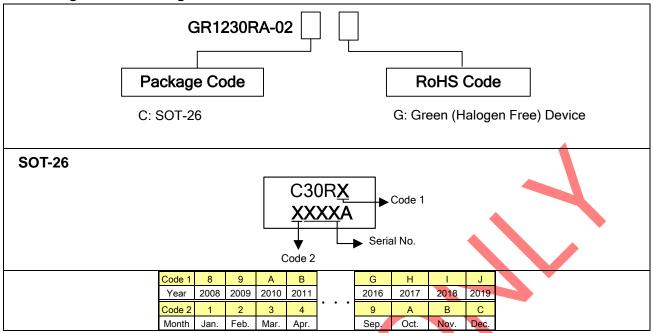
- Switching AC/DC power adapter
- SMPS Power Supply

Typical Application Information

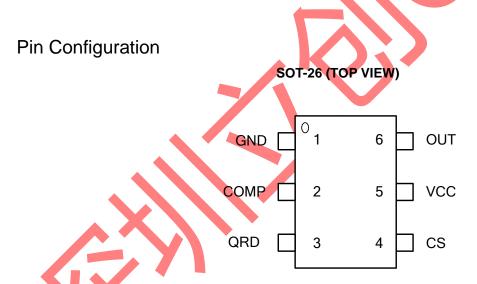




Ordering and Marking Information



Grenergy OPTO Inc. reserves the right to make changes to improve reliability or manufacture ability without notice, and advise customers to obtain the latest version of relevant information to verify before placing orders.



Pin Description

Pin No.	Name	Function
1	GND	Ground reference pin
2	COMP	Voltage feedback pin, by connecting a photo-coupler to control the duty cycle
3	QRD	This pin is for quasi-resonant detection and OVP.
4	cs	Current sense pin, connected to sense resistor for sensing the MOSFET current signal
5	VCC	Power supply pin
6	OUT	The output driver for driving the external MOSFET



Absolute Maximum Ratings

Supply voltage VCC 30
COMP, CS, QRD
OUT
Junction temperature 150
Storage temperature range
SOT-26 package thermal resistance250°C/
Power dissipation (SOT-26, at ambient temperature = 85° C) 250m
Lead temperature (SOT-26, soldering, 10 sec) 230
Lead temperature (All Pb free packages, soldering, 10 sec) 260
ESD, human body model 2.5k
ESD, machine model250 Caution: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot I
guaranteed and may cause permanent damage to the IC. These are stress ratings only and function
operation of the device at these or any other condition beyond those indicated in the Electrical Characteristi
section of the specification is not implied. The "Electrical Characteristics" table defines the conditions f
actual device operation. Exposure to absolute maximum rated conditions for extended periods may affect the conditions are likeliked.
device reliability

Recommended Operating Conditions

Item	Min.	Max.	Unit
Operating Junction temperature	-40	125	${\mathbb C}$
Operating ambient temperature	-40	85	${\mathbb C}$
Start Up Resistor (AC Half side)	540k	2.2M	Ω
Supply voltage VCC	9.5	26.5	V
VCC Capacitor	2.2	10	μF
COMP pin paralleling capacitor	1	33	nF
CS pin paralleling capacitor	100	1000	pF

Note:

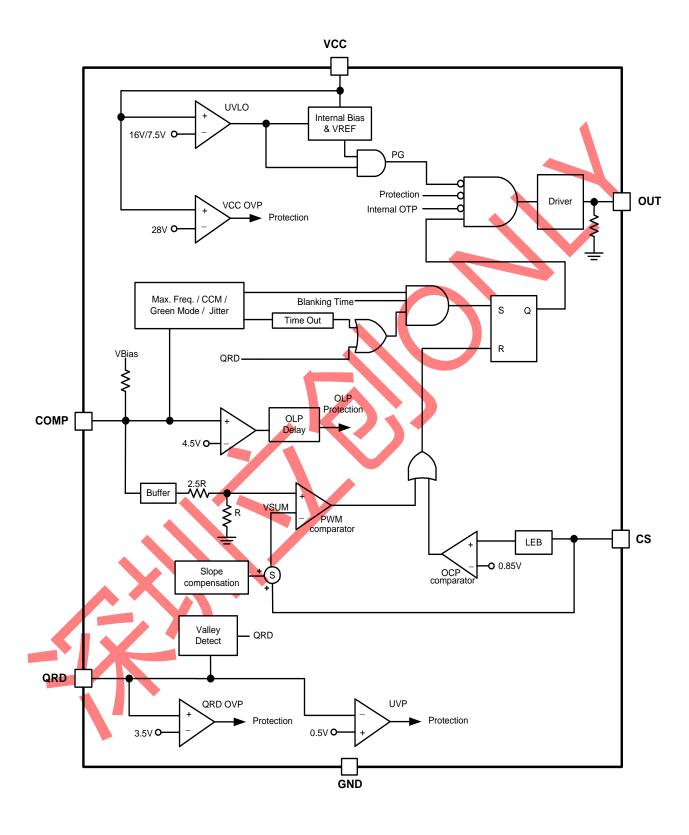
- Not to exceed the maximum junction temperature of the IC, this relates to the operating power of the IC and the thermal resistance of the IC-package as above.
- The small signal components should be placed to IC pin as possible.
- It's essential to connect VCC pin with a SMD ceramic capacitor (0.1μF~0.47μF) to filter out the undesired switching noise for stable operation.
- Connecting a capacitor to COMP pin is also essential to filter out the undesired switching noise for stable operation.
- Suggest using electrolytic capacitor or 1206 SMD ceramic capacitor as the VCC capacitor to avoid the acoustic noise from MLCC piezoelectric effect.

Protection Mode

CCM Switching Frequency	OLP/UVP	VCC OVP	QRD OVP
65kHz	Auto recovery	Auto recovery	Auto recovery



Block Diagram





Electrical Characteristics (TA = +25°C unless otherwise stated, VCC = 15.0V)

UVLO-ON 15.2 16.0 16.8 V VCC Mode Entry Point 8 8.5 9 V Hysteresis 0.25 V OVP level on VCC pin 27 28 29 V OVP level on VCC pin Debounce Time* 100 128 150 μs VOLTAGE FEEDBACK (COMP Pin) Short circuit current, Vcomp = 0V 180 230 280 uA Open loop voltage, COMP pin open 4.8 5.2 5.6 V Maximum Frequency Threshold, V _{SMAX} * 1.7 V Green Mode Threshold* 1.35 V Burst Mode Voltage 0.28 0.38 0.48 V Hysteresis 100 mV CURRENT SENSING (CS Pin) Maximum input voltage at Low Line, Vcsmax(ON Time>4us*) 0.80 0.85 0.90 V Maximum input voltage at High Line, VcsmaxL(ON Time<3.5us*) 0.725 V Internal Slope Compensation 0.3 V Leading-edge blanking time <t< th=""><th>Parameter</th><th>Min.</th><th>Тур.</th><th>Max.</th><th>Unit</th></t<>	Parameter	Min.	Тур.	Max.	Unit
Operating current (with 1nF load on OUT pin), Vcomp = 0V 0.65 mA Operating current (with 1nF load on OUT pin), Vcomp = 2.5V 1.8 mA Operating current (with 1nF load on OUT pin), protection tripped (VCC OVP, OLP, QRD OVP/UVP) 0.65 mA UVLO-OFF 7.0 7.5 8.0 V UVLO-ON 15.2 16.0 16.8 V VCC Mode Entry Point 8 8.5 9 V Hysteresis 0.25 V OVP level on VCC pin 27 28 29 V VOVP level on VCC pin Debounce Time* 400 128 15.0 µs VOP level on VCC pin Debounce Time* 400 128 15.0 µs Short circuit current, Vcomp = 0V 180 230 280 µA Open loop voltage, COMP pin open 4.8 5.2 5.6 V Maximum Frequency Threshold, V _{SMAX} * 1.7 V Green Mode Threshold* 1.35 V Burst Mode Voltage 0.28 0.38 0.48 V	SUPPLY VOLTAGE (VCC Pin)				
Operating current (with 1nF load on OUT pin), Vcomp = 2.5V 1.8	Startup current VCC=UVLO ON-0.1V	0.75	1.5	2	uA
Operating current (with 1nF load on OUT pin), protection tripped (VCC OVP, OLP, QRD OVP/UVP)	Operating current (with 1nF load on OUT pin), Vcomp = 0V		0.65		mA
(VCC OVP, OLP, QRD OVP/UVP) 0.65 mA UVLO-OFF 7.0 7.5 8.0 ∨ UVLO-ON 15.2 16.0 15.8 ∨ VCC Mode Entry Point 8 8.5 9 ∨ Hysteresis 0.25 ∨ ∨ OVP level on VCC pin 27 28 29 ∨ OVP level on VCC pin Debounce Time* 100 128 150 µs VOLTAGE FEEDBACK (COMP Pin) Short circuit current, Vcomp = 0V 180 230 280 µA Open loop voltage, COMP pin open 4.8 5.2 5.6 ∨ Maximum Frequency Threshold, V _{SMAX} * 1.7 ∨ V Green Mode Threshold* 1.35 ∨ V Burst Mode Voltage 0.28 0.38 0.48 ∨ Hysteresis 100 mV M CURRENT SENSING (CS Pin) Maximum input voltage at Law Line, VcsmaxL(ON Time>4us*) 0.80 0.85 0.90 ∨ Maximum input vo	Operating current (with 1nF load on OUT pin), Vcomp = 2.5V		1.8		mA
(VCC OVP, OLP, QRD OVP/UVP) 7.0 7.5 8,0 V UVLO-OFF 7.0 7.5 8,0 V UVLO-ON 15.2 16.0 16.8 V VCC Mode Entry Point 8 8.5 9 V Hysteresis 0.25 V V OVP level on VCC pin 27 28 29 V OVP level on VCC pin Debounce Time* 100 128 150 µs VOLTAGE FEEDBACK (COMP Pin) Short circuit current, Vcomp = 0V 180 230 280 UA Open loop voltage, COMP pin open 4.8 5.2 5.6 V Maximum Frequency Threshold, V _{SMAX} * 1.7 V Green Mode Threshold* 1.35 V Burst Mode Voltage 0.28 0.38 0.48 V CURRENT SENSING (CS Pin) Maximum input voltage at Low Line, Vosmax(ON Time>4us*) 0.80 0.85 0.90 V Maximum input voltage at High Line, Vosmax(ON Time>3.5us*) 0.725 V Internal Slope Compensation 0.3 V <td>Operating current (with 1nF load on OUT pin), protection tripped</td> <td></td> <td>0.05</td> <td></td> <td> A</td>	Operating current (with 1nF load on OUT pin), protection tripped		0.05		A
UVLO-ON 15.2 16.0 16.8 V VCC Mode Entry Point 8 8.5 9 V Hysteresis 0.25 V V OVP level on VCC pin 27 28 29 V OVP level on VCC pin Debounce Time* 100 128 150 μs VOLTAGE FEEDBACK (COMP Pin) Short circuit current, Vcomp = 0V 180 230 280 uA Open loop voltage, COMP pin open 4.8 5.2 5.6 V Maximum Frequency Threshold, V _{SMAX} * 1.7 V Green Mode Threshold* 1.35 V Burst Mode Voltage 0.28 0.38 0.48 V Hysteresis 100 mV CURRENT SENSING (CS Pin) Maximum input voltage at Low Line, Vcsmax(ON Time>4us*) 0.80 0.85 0.90 V Maximum input voltage at High Line, VcsmaxL(ON Time<3.5us*)	(VCC OVP, OLP, QRD OVP/UVP)		0.65		mA
VCC Mode Entry Point 8 8.5 9 V Hysteresis 0.25 V OVP level on VCC pin 27 28 29 V OVP level on VCC pin Debounce Time* 100 128 150 μs VOLTAGE FEEDBACK (COMP Pin) Short circuit current, Vcomp = 0V 180 230 280 UA Open loop voltage, COMP pin open 4.8 5.2 5.6 V Maximum Frequency Threshold, V _{SMAX} * 1.7 V Green Mode Threshold* 1.35 V Burst Mode Voltage 0.28 0.38 0.48 V Hysteresis 100 mV CURRENT SENSING (CS Pin) m 0.80 0.85 0.90 V Maximum input voltage at Low Line, VcsmaxL(ON Time>4us*) 0.80 0.85 0.90 V Maximum input voltage at High Line, VcsmaxL(ON Time>4us*) 0.725 V Internal Slope Compensation 0.3 V Leading-edge blanking time 270 350 430 <	UVLO-OFF	7.0	7.5	8.0	V
Hysteresis County Count	UVLO-ON	15.2	16.0	16.8	V
OVP level on VCC pin 27 28 29 V OVP level on VCC pin Debounce Time* 100 128 150 μs VOLTAGE FEEDBACK (COMP Pin) Short circuit current, Vcomp = 0V 180 230 280 uA Open loop voltage, COMP pin open 4.8 5.2 5.6 V Maximum Frequency Threshold, V _{SMAX} * 1.7 V Green Mode Threshold* 1.35 V Burst Mode Voltage 0.28 0.38 0.48 V Hysteresis 100 mV CURRENT SENSING (CS Pin) Maximum input voltage at Low Line, Vcsmax(ON Time>4us*) 0.80 0.85 0.90 V Maximum input voltage at High Line, VcsmaxL(ON Time<3.5us*)	VCC Mode Entry Point	8	8.5	9	V
OVP level on VCC pin Debounce Time* 100 128 150 μs VOLTAGE FEEDBACK (COMP Pin) Short circuit current, Vcomp = 0V 180 230 280 uA Open loop voltage, COMP pin open 4.8 5.2 5.6 V Maximum Frequency Threshold, V _{SMAX} * 1.7 V Green Mode Threshold* 1.35 V Burst Mode Voltage 0.28 0.38 0.48 V Hysteresis 100 mV CURRENT SENSING (CS Pin) mV Maximum input voltage at Low Line, Vcsmax(ON Time>4us*) 0.80 0.85 0.90 V Maximum input voltage at High Line, VcsmaxL(ON Time<3.5us*) 0.725 V Internal Slope Compensation 0.3 V Leading-edge blanking time 270 350 430 ns Input impedance 1 MΩ 0 ns QRD (QRD Pin) Upper Clamp Level, IZCD=0.5mA 4.3 4.6 4.9 V Lower Clamp Level, IZCD=-0.3mA 4.3 4.6 4.9 V	Hysteresis		0.25		V
VOLTAGE FEEDBACK (COMP Pin) Short circuit current, Vcomp = 0V 180 230 280 uA Open loop voltage, COMP pin open 4.8 5.2 5.6 V Maximum Frequency Threshold, V _{SMAX} * 1.7 V Green Mode Threshold* 1.35 V Burst Mode Voltage 0.28 0.38 0.48 V Hysteresis 100 mV CURRENT SENSING (CS Pin) mV Maximum input voltage at Lew Line, Vcsmax(ON Time>4us*) 0.80 0.85 0.90 V Maximum input voltage at High Line, VcsmaxL(ON Time<3.5us*)	OVP level on VCC pin	27	28	29	V
Short circuit current, Vcomp = 0V	OVP level on VCC pin Debounce Time*	100	128	150	μs
Open loop voltage, COMP pin open 4.8 5.2 5.6 V Maximum Frequency Threshold, V _{SMAX} * 1.7 V Green Mode Threshold* 1.35 V Burst Mode Voltage 0.28 0.38 0.48 V Hysteresis 100 mV CURRENT SENSING (CS Pin) Maximum input voltage at Low Line, Vcsmax(ON Time>4us*) 0.80 0.85 0.90 V Maximum input voltage at High Line, VcsmaxL(ON Time<3.5us*)	VOLTAGE FEEDBACK (COMP Pin)				
Maximum Frequency Threshold, V _{SMAX} * 1.7 V Green Mode Threshold* 1.35 V Burst Mode Voltage 0.28 0.38 0.48 V Hysteresis 100 mV CURRENT SENSING (CS Pin) Maximum input voltage at Low Line, Vcsmax(ON Time>4us*) 0.80 0.85 0.90 V Maximum input voltage at High Line, VcsmaxL(ON Time<3.5us*)	Short circuit current, Vcomp = 0V	180	230	280	uA
Single Mode Threshold* 1.35 V	Open loop voltage, COMP pin open	4.8	5.2	5.6	V
Burst Mode Voltage 0.28 0.38 0.48 V	Maximum Frequency Threshold, V _{SMAX} *		1.7		V
Hysteresis 100 mV	Green Mode Threshold*		1.35		V
CURRENT SENSING (CS Pin) Maximum input voltage at Low Line, Vcsmax(ON Time>4us*) 0.80 0.85 0.90 V Maximum input voltage at High Line, VcsmaxL(ON Time<3.5us*)	Burst Mode Voltage	0.28	0.38	0.48	V
Maximum input voltage at Low Line, Vcsmax(ON Time>4us*) 0.80 0.85 0.90 V Maximum input voltage at High Line, VcsmaxL(ON Time<3.5us*) 0.725 V Internal Slope Compensation* 0.3 V Leading-edge blanking time 270 350 430 ns Input impedance 1 MΩ Delay to Qutput* 100 200 ns QRD (QRD Pin) Upper Clamp Level, IZCD=0.5mA 4.3 4.6 4.9 V Lower Clamp Level, IZCD=0.3mA -0.3 V QRD Blanking Time 2 2.5 3 μs QRD OVP 3.38 3.5 3.62 V OVP De-bounce Time* 0.4 0.5 0.6 V	Hysteresis		100		mV
Maximum input voltage at High Line, VcsmaxL(ON Time<3.5us*)	CURRENT SENSING (CS Pin)		_		
Internal Slope Compensation* 0.3 V	Maximum input voltage at Low Line, Vcsmax(ON Time>4us*)	0.80	0.85	0.90	V
Leading-edge blanking time 270 350 430 ns Input impedance 1 M Ω Delay to Output* 100 200 ns QRD (QRD Pin) Upper Clamp Level, IZCD=0.5mA 4.3 4.6 4.9 V Lower Clamp Level, IZCD=-0.3mA -0.3 V QRD Blanking Time 2 2.5 3 μs QRD OVP 3.38 3.5 3.62 V OVP De-bounce Time* 128 μs UVP Level 0.4 0.5 0.6 V	Maximum input voltage at High Line, VcsmaxL(ON Time<3.5us*)		0.725		V
Input impedance 1 M Ω Delay to Output* 100 200 ns QRD (QRD Pin) Upper Clamp Level, IZCD=0.5mA 4.3 4.6 4.9 V Lower Clamp Level, IZCD=-0.3mA -0.3 V QRD Blanking Time 2 2.5 3 μs QRD OVP 3.38 3.5 3.62 V OVP De-bounce Time* 128 μs UVP Level 0.4 0.5 0.6 V	Internal Slope Compensation*		0.3		V
Delay to Output* 100 200 ns QRD (QRD Pin) Upper Clamp Level, IZCD=0.5mA 4.3 4.6 4.9 V Lower Clamp Level, IZCD=-0.3mA -0.3 V QRD Blanking Time 2 2.5 3 μs QRD OVP 3.38 3.5 3.62 V OVP De-bounce Time* 128 μs UVP Level 0.4 0.5 0.6 V	Leading-edge blanking time	270	350	430	ns
QRD (QRD Pin) Upper Clamp Level, IZCD=0.5mA 4.3 4.6 4.9 V Lower Clamp Level, IZCD=-0.3mA -0.3 V QRD Blanking Time 2 2.5 3 μs QRD OVP 3.38 3.5 3.62 V OVP De-bounce Time* 128 μs UVP Level 0.4 0.5 0.6 V	Input impedance	1			$M\Omega$
Upper Clamp Level, IZCD=0.5mA 4.3 4.6 4.9 V Lower Clamp Level, IZCD=-0.3mA -0.3 V QRD Blanking Time 2 2.5 3 μs QRD OVP 3.38 3.5 3.62 V OVP De-bounce Time* 128 μs UVP Level 0.4 0.5 0.6 V	Delay to Output*		100	200	ns
Lower Clamp Level, IZCD=-0.3mA -0.3 V QRD Blanking Time 2 2.5 3 μs QRD OVP 3.38 3.5 3.62 V OVP De-bounce Time* 128 μs UVP Level 0.4 0.5 0.6 V	QRD (QRD Pin)				
QRD Blanking Time 2 2.5 3 μs QRD OVP 3.38 3.5 3.62 V OVP De-bounce Time* 128 μs UVP Level 0.4 0.5 0.6 V	Upper Clamp Level, IZCD=0.5mA	4.3	4.6	4.9	V
QRD OVP 3.38 3.5 3.62 V OVP De-bounce Time* 128 μs UVP Level 0.4 0.5 0.6 V	Lower Clamp Level, IZCD=-0.3mA		-0.3		V
OVP De-bounce Time* 128 μs UVP Level 0.4 0.5 0.6 V	QRD Blanking Time	2	2.5	3	μs
UVP Level 0.4 0.5 0.6 V	QRD OVP	3.38	3.5	3.62	V
	OVP De-bounce Time*		128		μs
UVP De-bounce Time after start-up* 8 ms	UVP Level	0.4	0.5	0.6	V
	UVP De-bounce Time after start-up*		8		ms

^{*}Guaranteed by Design.



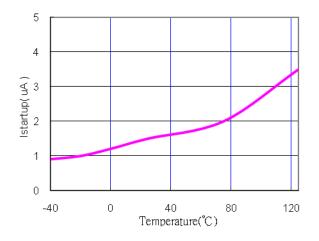
Electrical Characteristics (TA = $+25^{\circ}$ C unless otherwise stated, VCC = 15.0V)

Parameter	Min.	Тур.	Max.	Unit
OSCILLATOR				
CCM Frequency	60	65	70	kHz
Maximum Frequency Clamp, Vcomp>V _{SMAX} *		69		kHz
Green Mode Frequency	21	25	29	kHz
Jitter Frequency (CCM, Vcomp>Vsmax)		±8		%
Soft Start Time (CS Pin)			N	
Soft Start Time*		8		ms
GATE DRIVER OUTPUT (OUT Pin)				
Output low level, VCC = 15V, Io = 20mA			1	V
Output high level, VCC = 15V, Out pin=1.5kΩ to GND	8	1		V
Output High Level, VCC=UVLO-OFF+0.2V	7		VCC	V
Rising time, load capacitance = 1000pF*	270	330	390	ns
Falling time, load capacitance = 1000pF*	30	45	50	ns
VGATE-clamp (VCC = 17V)		13.5		V
Maximum On Time (CCM Fs=70kHz)	9.79	10.8	12.0	μs
Open Loop Protection (COMP Pin)				
OLP trip level, Vcomp	4.2	4.35	4.5	>
OLP delay time after start-up	55	69	84	ms
Internal OTP (Guaranteed by design)				
OTP*		145		°C
Hysteresis*		30		°C

^{*}Guaranteed by Design.



Typical Performance Characteristics



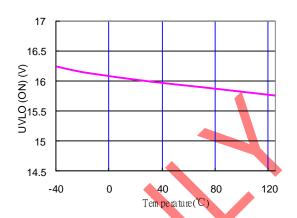
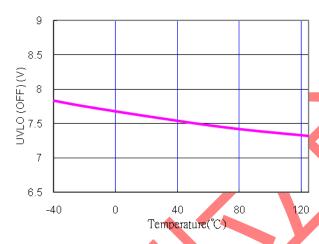


Fig. 1 Istartup current vs. Temperature

Fig. 2 UVLO (ON) vs. Temperature



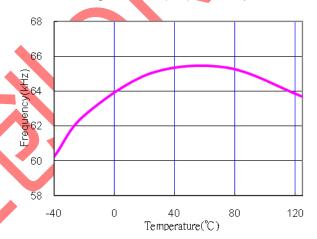
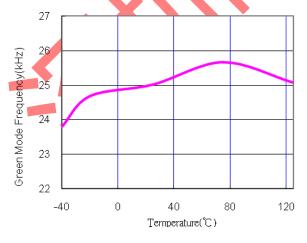


Fig. 3 UVLO (OFF) vs. Temperature

Fig. 4 CCM Frequency vs. Temperature



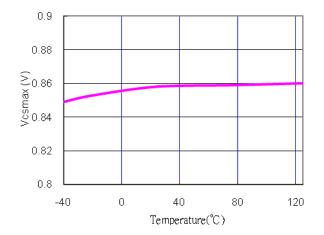


Fig. 5 Green Mode Frequency vs. Temperature

Fig. 6 Vcsmax vs. Temperature



Typical Performance Characteristics

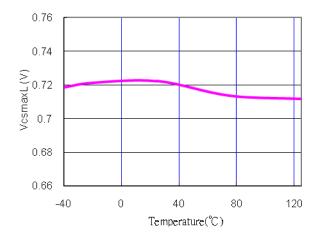


Fig. 7 VcsmaxL vs. Temperature

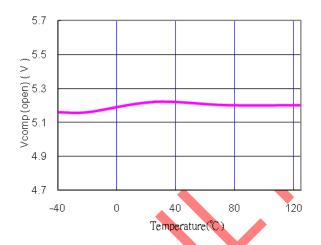


Fig. 8 Vcomp open loop voltage vs. Temperature

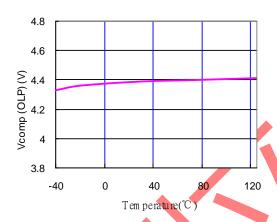


Fig. 9 Vcomp (OLP) vs. Temperature

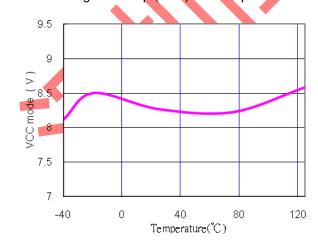


Fig. 11 VCC Mode (Entry) vs. Temperature

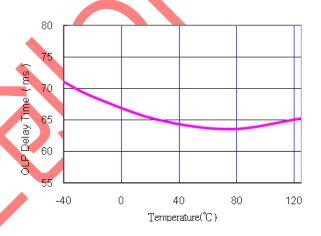


Fig. 10 OLP delay time vs. Temperature

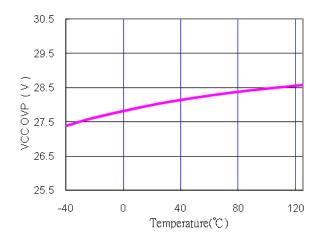


Fig. 12 VCC OVP vs. Temperature



Application Information

Overview

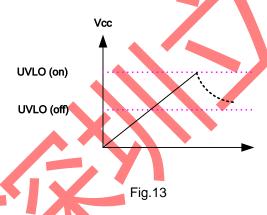
The GR1230RA-02 is a high performance multi-mode (QR/CCM) PWM controller for flyback converter. This results in a low-cost solution for low power AC/DC adapters. It integrated more functions to reduce the external components counts and the size. Its major features are described as below.

Start-up Current

The typical start-up current is 1.5uA. Very low start-up current allows the PWM controller to increase the value of start-up resistor and then reduce the power dissipation on it.

Under-voltage Lockout (UVLO)

A hysteresis UVLO comparator is implemented in GR1230RA-02, then the turn-on and turn-off thresholds level are fixed at 16V and 7.5V respectively. This hysteresis shown in Fig.13 ensures that the start-up capacitor will be adequate to supply the chip during start-up.



Multi-Mode Operation for High Efficiency

GR1230RA-02 is a multi-mode QR/CCM controller. The controller changes the mode of operation according to switching frequency and comp pin voltage, as shown in the Fig.14. At the normal operating condition, the IC operates in QR mode to reduce the switching loss. In the QR mode, the frequency varies depending on the line voltage and the load conditions. As the output load current is increased, the on-time T_{ON} is increased, and thus

the switching frequency decreases. If the switching frequency lowers than 65kHz frequency, the controller adaptively transitions to a CCM mode. Thus, small size transformer can be used with high power conversion efficiency.

As the output load current is decreased, the on-time T_{ON} is decreased, and thus the switching frequency increases. If the switching frequency increases till over the clamp of 69kHz, IC will skip the first valley to turn on in 2^{nd} or 3^{rd} valley.

At light load conditional, the VCOMP is lower than V_{SG1} and the system operates in green mode for high power conversion efficiency. The max switching frequency clamp will start to linearly decrease from 69kHz to 25kHz. The valley switching characteristic is still preserved in green mode. That is, when load decreases, the system automatically skip more and more valleys and the switching frequency is thus reduced.

At zero load or very light load conditions (Vcomp< Burst mode voltage), the gate output pin of the GR1230RA-02 will be disabled immediately under such condition, enhancing power saving.

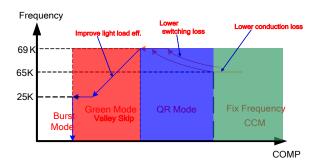


Fig.14

Quasi-Resonant Detection

The QR detection block will detect auxiliary winding voltage to turn on the MOSFET. The time-out2 generates a MOSFET turn-on signal as the driver output drops to low level for more than 150µs (Time Out) with the falling edge of the driver output.



Leading-edge Blanking (LEB)

Each time the power MOSFET is switched on, a turn-on spike will inevitably occur at the sense resistor. To avoid fault trigger, a leading-edge blanking time is built in. During this blanking period, the current-limit comparator is disabled and cannot switch off the gate driver.

Internal Slope Compensation

A built-in slope compensation circuit is constructed in GR1230RA-02. When the switch is on, a ramp voltage is added to the sensed voltage across the CS pin, which helps to stabilize the system and prevent sub-harmonic oscillations.

Over-voltage Protection (OVP) on Auto

Recovery mode

To prevent power MOSFET from being damaged, the GR1230RA-02 is implemented an OVP function on VCC. When the VCC voltage is higher than the OVP threshold voltage, the output gate driver circuit will be shut down immediately to stop the switching of power MOSFET. The VCC OVP function is an auto-recovery type protection. If OVP happens, the pulses will be stopped and recover at the next UVLO on. The GR1230RA-02 is working in a hiccup mode as shown in Fig. 15.

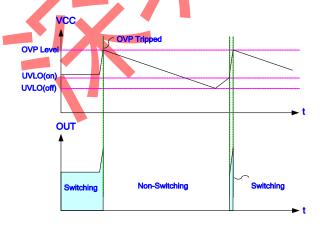


Fig.15

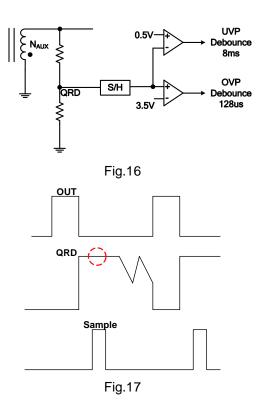
Output OVP on QRD - Auto Recovery mode

An output overvoltage protection is implemented in the GR1230RA-02, as shown in Fig. 16 and 17. It senses the auxiliary voltage via the divided resistors. The overvoltage protection works by sampling the plateau voltage after a delay time. The sampling voltage level is compared with internal threshold voltage 3.5V. If the sampling voltage exceeds the QRD OVP trip level, the QRD OVP circuit switches the power MOSFET off. The QRD OVP function is an auto-recovery type protection. The de-bounce time of QRD OVP is 128µs to prevent incorrect OVP detection which might occur during ESD or lightning events.

Output Under-voltage Protection (UVP) on

QRD- Auto Recovery mode

To protect the circuit from damage due to output short condition, an auto-recovery type of UVP protection is implemented for it. If the QRD voltage declines below 0.5V for over the 8ms, the protection will be activated to turn off the gate until the next UVLO-ON.





OLP (Open Loop Protection) - Auto

Recovery mode

The GR1230RA-02 has open loop protection function. An internal circuit detects the Vcomp level, when the Vcomp is larger than an OLP threshold level and continues over OLP delay time, the protection will be activated and then turn off the gate output to stop the switching of power circuit. Then VCC decreases below UVLO off level, the controller resets again.

Gate Clamp/Soft Driving

Driver output is clamped by an internal 13.5V clamping circuit to prevent from undesired over-voltage gate signals. And under the conditions listed below, the gate output will turn off immediately to protect the power circuit. The GR1230RA-02 also has soft driving function to minimize EMI.

VCC Mode Operation

In order to avoid the output voltage shut down by load changing from full to no load, the GR1230RA-02 is built-in the VCC mode function. When the load from full changes to no load, the output voltage will overshoot and pull low the COMP pin by feedback loop (Into burst mode). Thus the

duty will disappear and no power delivers to the secondary. If there is without any mechanism to prevent this situation, the VCC pin voltage will down to UVLO off and the IC will re-start again. In the GR1230RA-02, before the VCC is down to UVLO off, it will force the OUT pin outputs the specified duty to pull the VCC higher than UVLO off.

The VCC mode function is used to prevent the output re-start again when load changes. So never let the system operate on the VCC mode at no load. The system should operate on burst mode, otherwise the input power maybe become larger.

Fault Protection

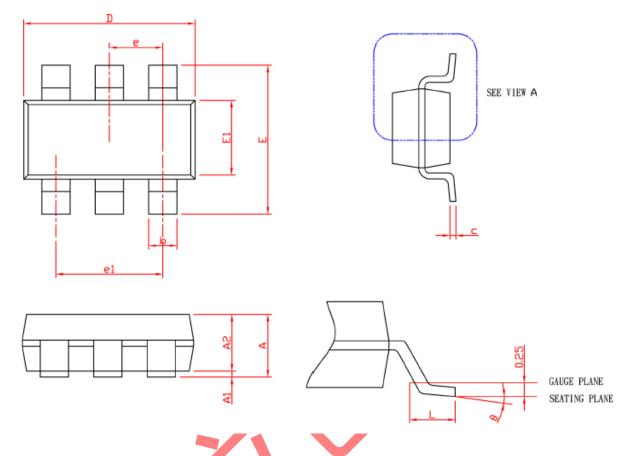
There are several critical protections integrated in the

- . CS pin floating
- . Comp pin shorting
- Comp pin floating
- . QRD pin shorting



Package Information

SOT-26



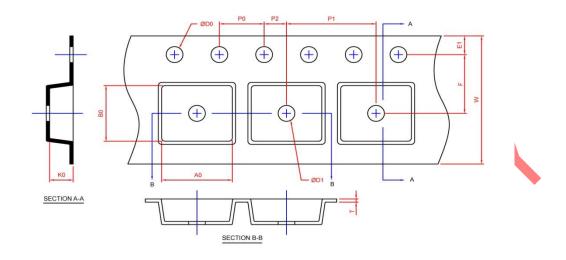
		SO [™]	Γ-26		
SYMBOL	MILLIN	IETERS	INCHES		
	MIN.	MAX.	MIN.	MAX.	
A		1.45		0.057	
A1	0.00	0.15	0.000	0.006	
A2	0.90	1.30	0.035	0.051	
b	0.30	0.50	0.012	0.020	
C	0.08	0.22	0.003	0.009	
D	2.70	3.10	0.106	0.122	
E	2.60	3.00	0.102	0.118	
E1	1.40	1.80	0.055	0.071	
е	0.95	BSC	0.037	BSC	
e1	1.90	BSC	0.075	BSC	
L	0.30	0.60	0.012	0.024	
θ	0°	8°	0°	8°	

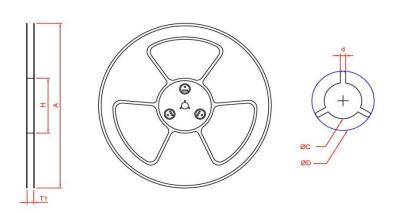
Note: 1. Followed from JEDEC MO-178 AB.

2. Dimension D and E1 do not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 10 mil per side



Carrier Tape & Reel Dimensions soт-26





Application	Α	Н	T1	С	d	D	W	E1	F
	178.0±2.00	50 MIN.	8.4+2.00 -0.00	13.0+0.50 -0.20	1.5 MIN.	20.2 MIN.	8.0±0.30	1.75±0.10	3.5±0.05
SOT-26	P0	P1	P2	D0	D1	Т	A0	В0	K0
	4.0±0.10	4.0±0.10	2.0±0.05	1.5+0.10 -0.00	1.0 MIN.	0.6+0.00 -0.40	3.20±0.20	3.10±0.20	1.50±0.20

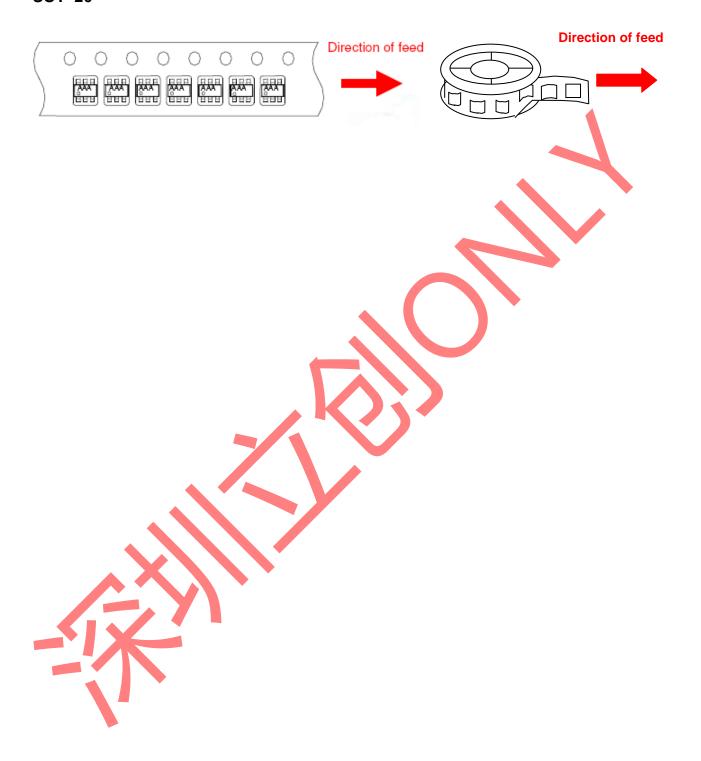
Application	Carrier Width	Cover Tape Width	Devices Per Reel
SOT -26	8	5.3	3000

(mm)



Tape and Specification Reel

SOT-26



Grenergy OPTO, Inc. reserves the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Switching Controllers category:

Click to view products by Grenergy manufacturer:

Other Similar products are found below:

LV5065VB-TLM-H LV5066V-TLM-H LV5725JAZ-AH 633888R MP2908AGF AZ7500EP-E1 NCP1012AP133G NCP1217P133G

NCP1218AD65R2G NCP1234AD100R2G NCP1244BD065R2G NCP1336ADR2G NCP1587GDR2G NCP6153MNTWG

NCP81005MNTWG NCP81101BMNTXG NCP81205MNTXG HV9123NG-G-M934 IR35207MTRPBF ISL6367HIRZ CAT874-80ULGT3

SJ6522AG SJE6600 TLE63893GV50XUMA1 IR35215MTRPBF SG3845DM NCP1216P133G NCP1236DD65R2G NCP1247BD100R2G

NCP1250BP65G NCP4202MNR2G NCP4204MNTXG NCP6132AMNR2G NCP81141MNTXG NCP81142MNTXG NCP81172MNTXG

NCP81203MNTXG NCP81206MNTXG NX2155HCUPTR UC3845ADM UBA2051C IR35201MTRPBF MAX8778ETJ+

MAX17500AAUB+T MAX17411GTM+T MAX16933ATIR/V+ NCP1010AP130G NCP1063AD100R2G NCP1216AP133G

NCP1217AP100G